

physica status solidi Young Researcher Award

is bestowed upon

H. Murakami

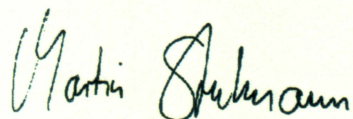
Tokyo University of Agriculture and Technology

for his/her contribution entitled

**Influence of growth temperature on the twin formation of the
InN{101⁻³} on GaAs(110) by metalorganic vapor phase epitaxy**

at the

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Nitride Semiconductors (ICNS-9)
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Editor-in-Chief
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Conference Chair
ICNS-9